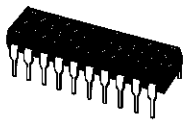
SGS-THOMSON MICROELECTRONICS

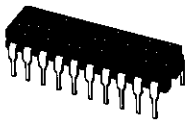
M54HC354
M74HC354

8 CHANNEL MULTIPLEXER/REGISTER (3 STATE)

- HIGH SPEED
  t_{PD} = 24 ns (TYP.) AT V_{CC} = 5 V
- LOW POWER DISSIPATION
  I_{CC} = 4 µA (MAX.) AT T_A = 25 °C
- HIGH NOISE IMMUNITY
  $V_{NIH} = V_{NIL}$ = 28 % V_{CC} (MIN.)
- OUTPUT DRIVE CAPABILITY
  15 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
  $|I_{OH}| = I_{OL}$ = 6 mA (MIN.)
- BALANCED PROPAGATION DELAYS
  $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
  V_{CC} (OPR) = 2 V TO 6 V
- PIN AND FUNCTION COMPATIBLE
  WITH 54/74LS354



B1R
(Plastic Package)



F1R
(Ceramic Package)

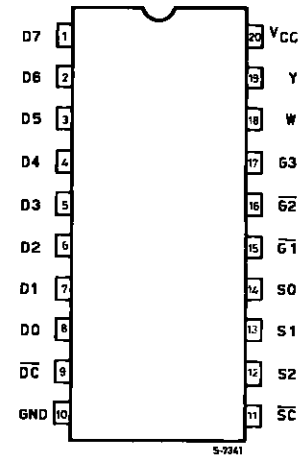
M1R
(Micro Package)

C1R
(Chip Carrier)

ORDER CODES :

M54HC354F1R M74HC354M1R
M74HC354B1R M74HC354C1R

PIN CONNECTIONS (top view)



NC =
No Internal
Connection

DESCRIPTION

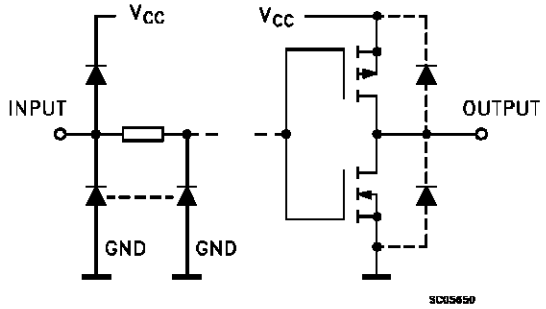
The M54/74HC354 is a high speed CMOS 8-CHANNEL MULTIPLEXER/REGISTER (3-state) fabricated in silicon gate C^2MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low consumption.

This device contains an 8 channel digital multiplexer with an 8-bit input data register and a 3-bit address input register with 3-state outputs. The one of eight input data will be provided on the Y output pin (non-inverted output) and W output pin (inverted output) determined by the address data.

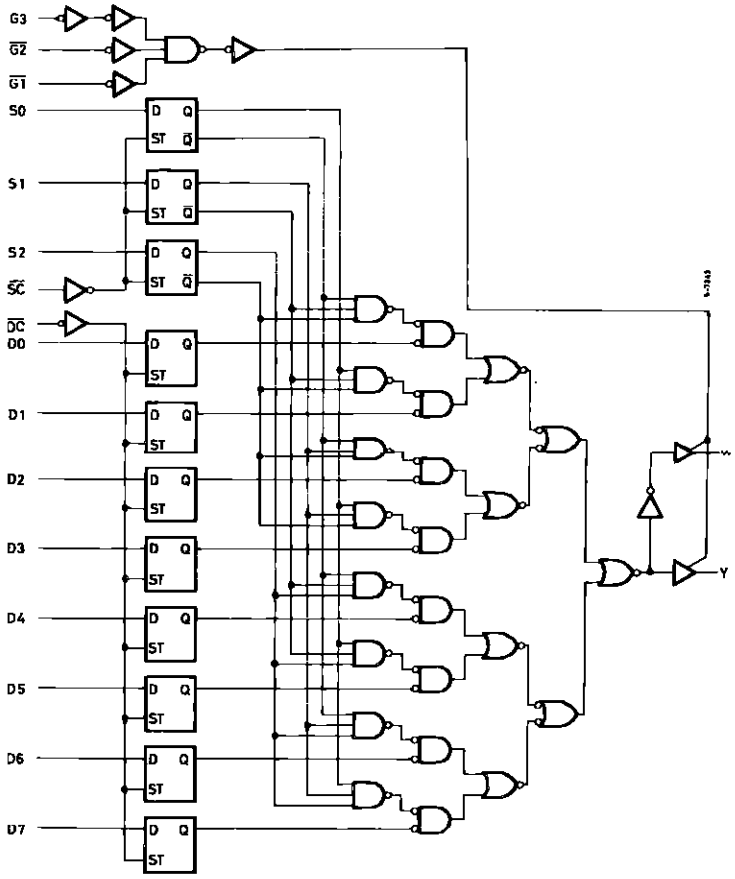
The information at the data inputs (D0 to D7) is stored in the 8-bit latch at the negative pulse on $\overline{DC}$ input. The information at the address inputs (S0 to S2) is stored in the 3-bit latch at the negative pulse on $\overline{SC}$ input. These outputs are disabled to be high-impedance when input $\overline{G1}$ is held high, input $\overline{G2}$ is held high or input G3 is held low. This device is suitable for interfacing with bus lines in a bus organized system.

The M54/74HC354 is similar in function to the M54/74HC356, which has an 8-bit flip-flop as the data register instead of an 8-bit latch. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

INPUT AND OUTPUT EQUIVALENT CIRCUIT



LOGIC DIAGRAM



TRUTH TABLE OF INTERNAL LATCH

INPUTS		OUTPUTS	
D	**ST**	**Q**	$\overline{\mathbf{Q}}$
L	H	L	H
H	H	H	L
X	L	Qn	$\overline{Qn}$

X: DON'T CARE

Qn: DATA STORED AT THE TRAILING EDGE OF THE MOST RECENT ST PULSE.

TRUTH TABLE

INPUTS							OUTPUTS	
SELECT *			$\overline{DC}$	OUTPUT ENABLES			W	Y
S2	S1	S0		G1	$\overline{G2}$	G3		
X	X	X	X	H	X	X	Z	Z
X	X	X	X	X	H	X	Z	Z
X	X	X	X	X	X	L	Z	Z
L	L	L	L	L	L	H	$\overline{D0}$	D0
L	L	L	H	L	L	H	$\overline{D0n}$	D0n
L	L	H	L	L	L	H	$\overline{D1}$	D1
L	L	H	H	L	L	H	$\overline{D1n}$	D1n
L	H	L	L	L	L	H	$\overline{D2}$	D2
L	H	L	H	L	L	H	$\overline{D2n}$	D2n
L	H	H	L	L	L	H	$\overline{D3}$	D3
L	H	H	H	L	L	H	$\overline{D3n}$	D3n
H	L	L	L	L	L	H	$\overline{D4}$	D4
H	L	L	H	L	L	H	$\overline{D4n}$	D4n
H	L	H	L	L	L	H	$\overline{D5}$	D5
H	L	H	H	L	L	H	$\overline{D5n}$	D5n
H	H	L	L	L	L	H	$\overline{D6}$	D6
H	H	L	H	L	L	H	$\overline{D6n}$	D6n
H	H	H	L	L	L	H	$\overline{D7}$	D7
H	H	H	H	L	L	H	$\overline{D7n}$	D7n

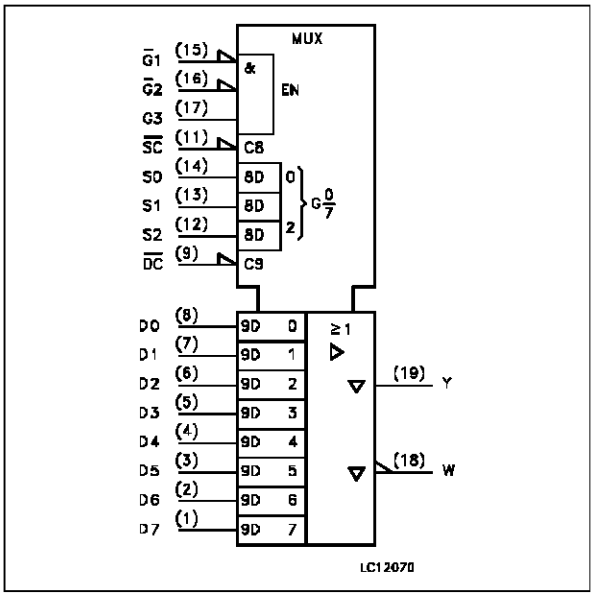
X: DON'T CARE Z: HIGH IMPEDANCE *: THISCOLUMN SHOWS THE INPUT ADDRESS SETUP WITH $\overline{SC}$ LOW

D0n ....D7n: THE LEVEL OF STEADY-STATE INPUTS AT INPUT DO THROUGH D7, RESPECTIVELY, BEFORE THE MOST RECENT LOW TO HIGH TRANSITION OF DATA CONTROL.

PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
8, 7, 6, 5, 4, 3, 2, 1	D0 to D7	Data Inputs
9	$\overline{DC}$	Data Enable Input (Active LOW)
11	$\overline{SC}$	Latch Enable Input (Active LOW)
14, 13, 12	SO, S1, S2	Select Inputs
15, 16	$\overline{G1}$, $\overline{G2}$	Output Enable Inputs (Active LOW)
17	G3	Output Enable Input (Active HIGH)
18	W	3 State Multiplexer Output (Active LOW)
19	Y	3 State Multiplexer Output (Active HIGH)
10	GND	Ground (0V)
20	V_{CC}	Positive Supply Voltage

IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 35	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 70	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
(*) 500 mW: ≅ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		2 to 6	V
V_I	Input Voltage		0 to V_{CC}	V
V_O	Output Voltage		0 to V_{CC}	V
T_{op}	Operating Temperature: **M54HC** Series **M74HC** Series		-55 to +125 -40 to +85	°C °C
t_r, t_f	Input Rise and Fall Time	V_{CC} = 2 V	0 to 1000	ns
		V_{CC} = 4.5 V	0 to 500	
		V_{CC} = 6 V	0 to 400	

DC SPECIFICATIONS

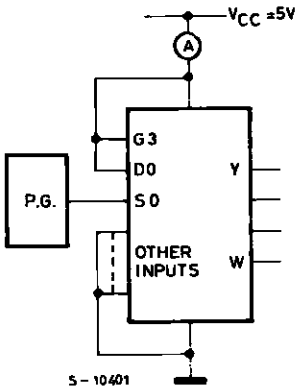
Symbol	Parameter	Test Conditions			Value							Unit
		V_{CC} (V)			T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0			1.5			1.5		1.5		V
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
V_{IL}	Low Level Input Voltage	2.0					0.5		0.5		0.5	V
		4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
V_{OH}	High Level Output Voltage	2.0	V_I = V_{IH} or V_{IL}	I_O=-20 µA	1.9	2.0		1.9		1.9		V
		4.5			4.4	4.5		4.4		4.4		
		6.0			5.9	6.0		5.9		5.9		
		4.5		I_O=-6.0 mA	4.18	4.31		4.13		4.10		
		6.0		I_O=-7.8 mA	5.68	5.8		5.63		5.60		
V_{OL}	Low Level Output Voltage	2.0	V_I = V_{IH} or V_{IL}	I_O= 20 µA		0.0	0.1		0.1		0.1	V
		4.5				0.0	0.1		0.1		0.1	
		6.0				0.0	0.1		0.1		0.1	
		4.5		I_O= 6.0 mA		0.17	0.26		0.33		0.40	
		6.0		I_O= 7.8 mA		0.18	0.26		0.33		0.40	
I_I	Input Leakage Current	6.0	V_I = V_{CC} or GND				±0.1		±1		±1	µA
I_{OZ}	3 State Output Off State Current	6.0	V_I = V_{IH} or V_{IL} V_O = V_{CC} or GND				±0.5		±5.0		±10	µA
I_{CC}	Quiescent Supply Current	6.0	V_I = V_{CC} or GND				4		40		80	µA

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input $t_r = t_f$ = 6 ns)

Symbol	Parameter	Test Conditions			Value							Unit
		V_{CC} (V)	C_L (pF)		T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0	50			25	60		75		90	ns
		4.5				7	12		15		18	
		6.0				6	10		13		15	
t_{PLH} t_{PHL}	Propagation Delay Time (Dn, $\overline{DC}$ - Y, W)	2.0	50			83	210		265		315	ns
		4.5				26	42		53		63	
		6.0				21	36		45		54	
		2.0	150			99	250		315		375	ns
		4.5				31	50		63		75	
		6.0				25	43		54		64	
t_{PLH} t_{PHL}	Propagation Delay Time (Sn - Y, W)	2.0	50			98	260		325		390	ns
		4.5				30	52		65		78	
		6.0				25	44		55		66	
		2.0	150			114	300		375		450	ns
		4.5				35	60		75		90	
		6.0				29	51		64		77	
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{SC}$ - Y, W)	2.0	50			102	270		340		405	ns
		4.5				31	54		68		81	
		6.0				27	46		58		69	
		2.0	150			118	310		390		465	ns
		4.5				36	62		78		93	
		6.0				31	53		66		79	
t_{PZL} t_{PZH}	3 State Output Enable Time	2.0	50	R_L = 1 KΩ		44	125		155		190	ns
		4.5				14	25		31		38	
		6.0				12	21		26		32	
		2.0	150	R_L = 1 KΩ		60	165		205		250	ns
		4.5				19	33		41		50	
		6.0				16	28		35		43	
t_{PLZ} t_{PHZ}	3 State Output Disable Time	2.0	50	R_L = 1 KΩ		42	155		195		235	ns
		4.5				20	31		39		47	
		6.0				17	26		33		40	
$t_{W(L)}$	Minimum Pulse Width (DC) (SC)	2.0	50			18	75		95		110	ns
		4.5				6	15		19		22	
		6.0				6	13		16		19	
t_s	Minimum Set-up Time (Dn) (Sn)	2.0	50			10	50		65		75	ns
		4.5				3	10		13		15	
		6.0				3	9		11		13	
t_h	Minimum Hold Time (Dn) (Sn)	2.0	50				5		5		5	ns
		4.5					5		5		5	
		6.0					5		5		5	
C_{IN}	Input Capacitance					5	10		10		10	pF
C_{PD} (*)	Power Dissipation Capacitance					77						pF

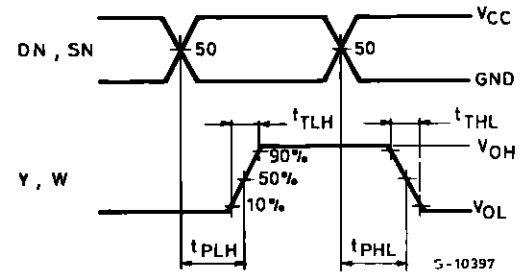
(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operting current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$

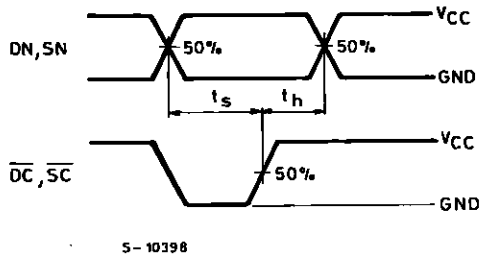
TEST CIRCUIT I_{CC} (Opr.)

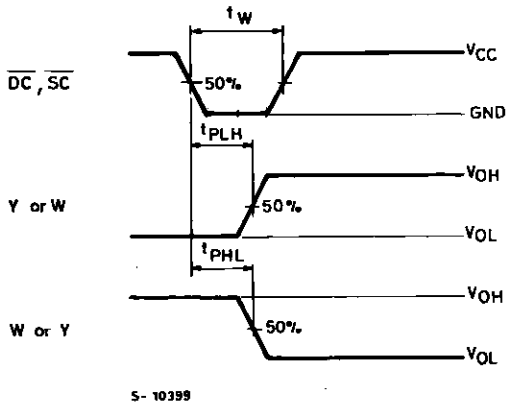


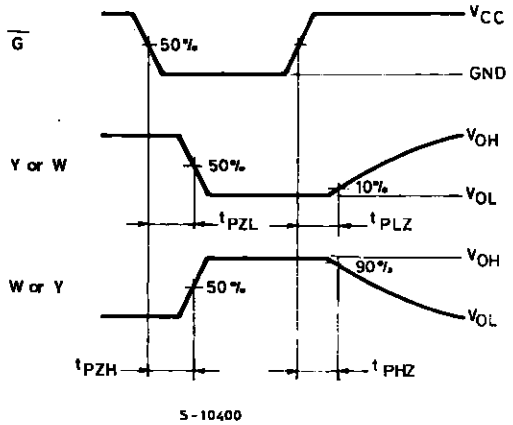
INPUT WAVEFORM IS THE SAME AS THAT IN CASE OF SWITCHING CHARACTERISTICS TEST.

SWITCHING CHARACTERISTICS TEST WAVEFORM



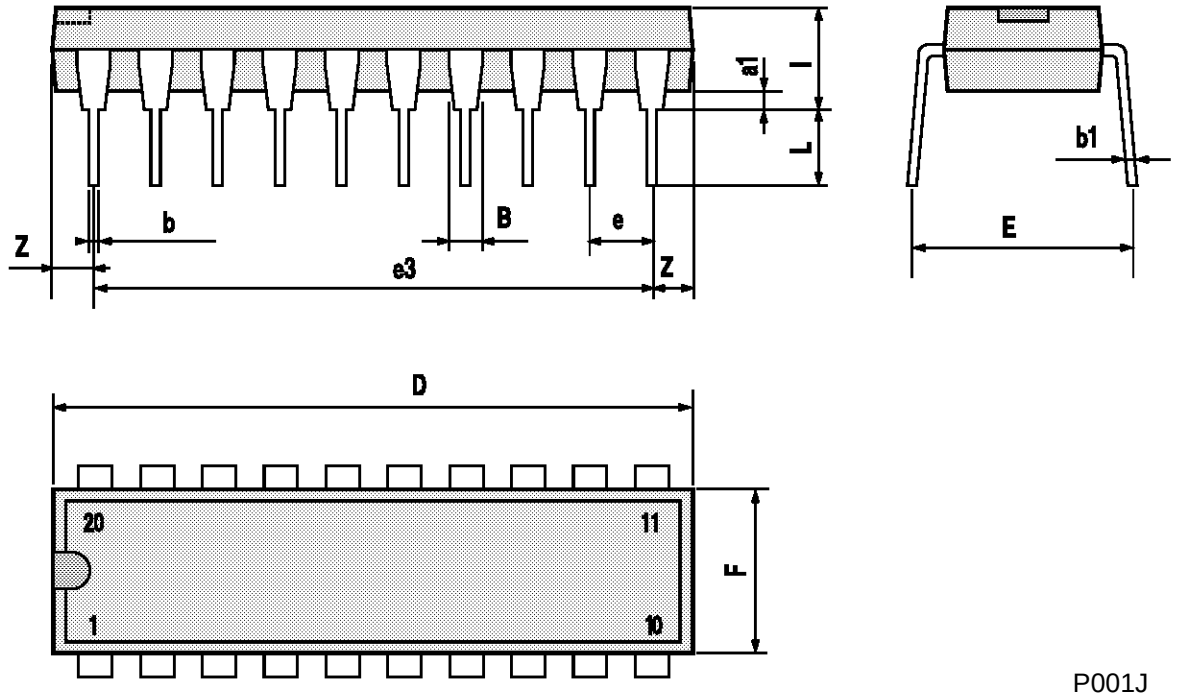






Plastic DIP20 (0.25) MECHANICAL DATA

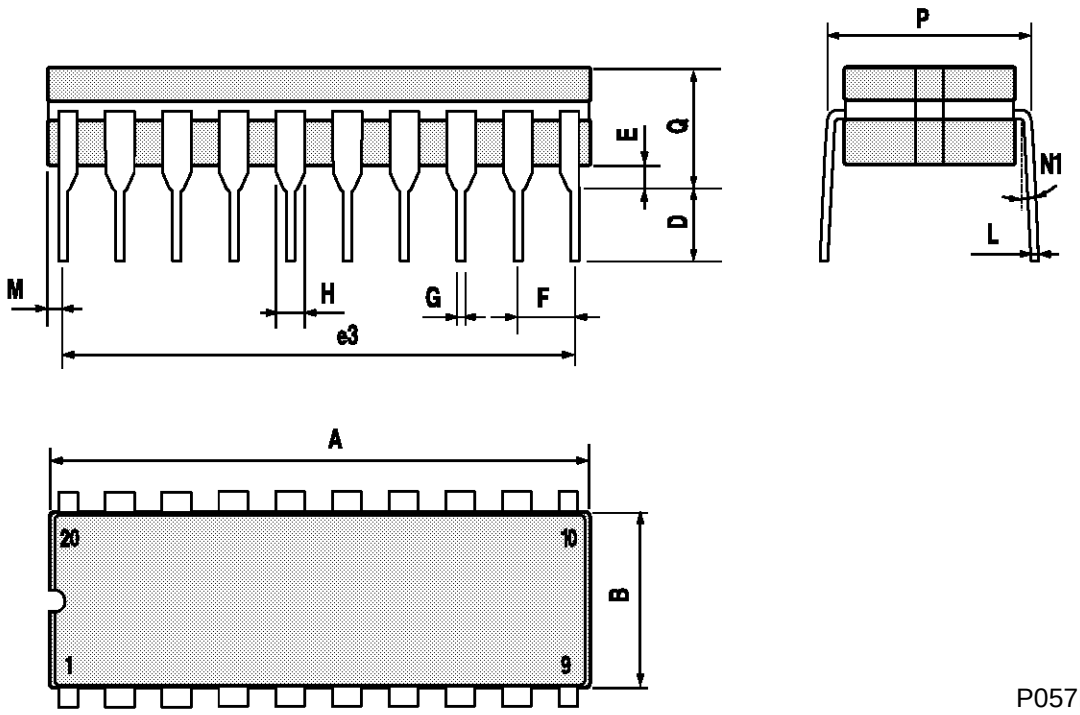
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.254			0.010		
B	1.39		1.65	0.055		0.065
b		0.45			0.018	
b1		0.25			0.010	
D			25.4			1.000
E		8.5			0.335	
e		2.54			0.100	
e3		22.86			0.900	
F			7.1			0.280
I			3.93			0.155
L		3.3			0.130	
Z			1.34			0.053



P001J

Ceramic DIP20 MECHANICAL DATA

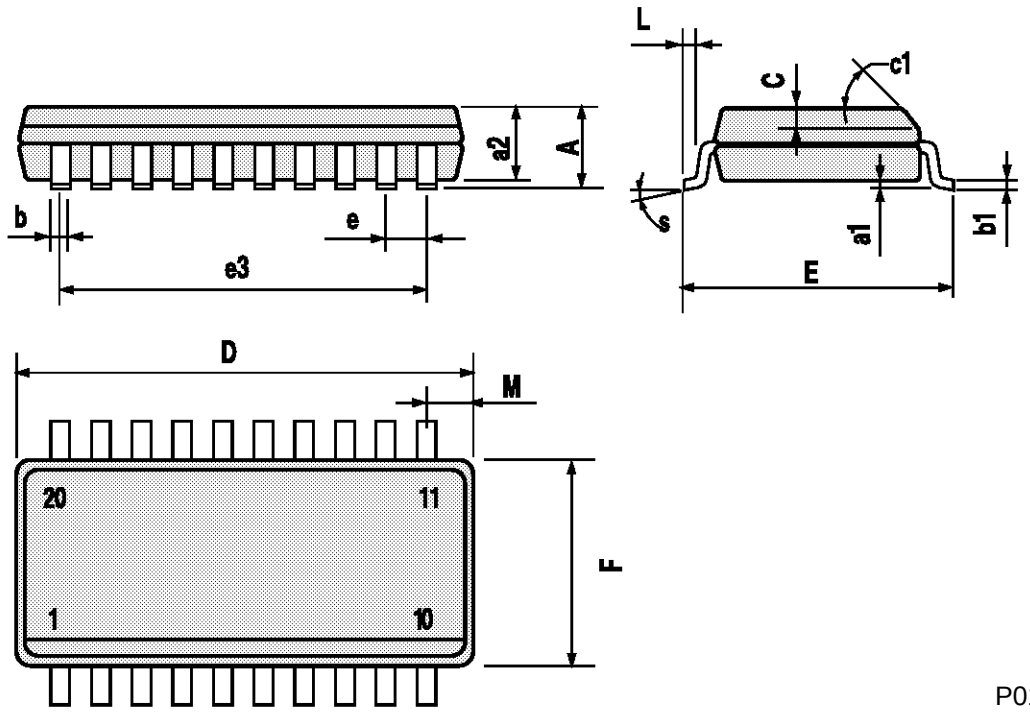
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			25			0.984
B			7.8			0.307
D		3.3			0.130	
E	0.5		1.78	0.020		0.070
e3		22.86			0.900	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
I	1.27		1.52	0.050		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N1	4° (min.), 15° (max.)					
P	7.9		8.13	0.311		0.320
Q			5.71			0.225



P057H

SO20 MECHANICAL DATA

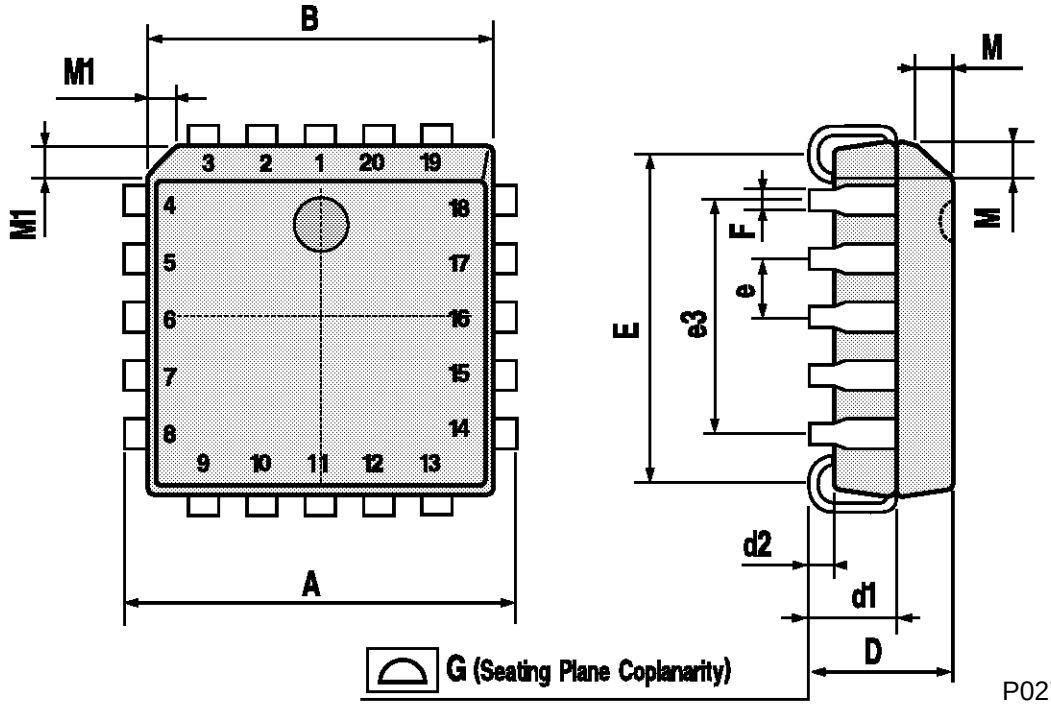
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.10		0.20	0.004		0.007
a2			2.45			0.096
b	0.35		0.49	0.013		0.019
b1	0.23		0.32	0.009		0.012
C		0.50			0.020	
c1	45° (typ.)					
D	12.60		13.00	0.496		0.512
E	10.00		10.65	0.393		0.419
e		1.27			0.050	
e3		11.43			0.450	
F	7.40		7.60	0.291		0.299
L	0.50		1.27	0.19		0.050
M			0.75			0.029
S	8° (max.)					



P013L

PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



P027A

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